03500.101486.

PATENT APPLICATION

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NOV 0 6 2006 W	IN THE UNITED STATES PATE	NT AN	ND TRADEMARK OFFICE
	plication of:):	
TOMO	NARI NAKAYAMA, et al.)	
Application No.: 10/559,799			
Int'l. Filing Date: June 9, 2005)	
For:	FIELD EFFECT TRANSISTOR AND PRODUCTION PROCESS THEREOF)	November 3, 2006

Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

INFORMATION DISCLOSURE STATEMENT

Sir:

In compliance with the duty of disclosure under 37 C.F.R. § 1.56 and in accordance with the practice under 37 C.F.R. §§ 1.97 and 1.98, the Examiner's attention is directed to the documents listed on the enclosed Form PTO-1449. Copies of the listed documents, other than the U.S. patent documents, are enclosed.

Japan 2004-63977, Japan 2004-63975, Japan 2004-128469, Japan 2004-6700, Japan 2004-146796, U.S. Patent No. 6,861,377, and U.S. Publication No. 2004/0131782 were cited in the International Search Report and/or Written Opinion which issued in the corresponding international application. A copy of the International Search Report and a copy of the Written Opinion are enclosed.

The following documents are discussed at the following pages of the specification:

	Page(s)
<u>Documents</u>	2
A. Assadi, et al., Appl. Phys. Lett., Vol. 53, No. 3,	2
July 18, 1988	2.
H. Fuchigami, et al., Appl. Phys. Lett., Vol. 63, No. 10,	2
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Japan 10-190001	3
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Janos Veres, et al., Advanced Functional Materials, Vol. 13,	
No. 3, March 2003	5
Zhenan Bao, et al., Chem. Mater., Vol. 9, No. 6, 1997	J

An English-language abstract for each of the Japanese documents listed on the Form PTO-1449 is enclosed.

According to a commercial database, U.S. Patent No. 6,861,377 is in the same patent family as Japan 2004-6700, U.S. Patent 6,107,117 is in the same patent family as Japan 10-190001, and U.S. Publication No. 2004/0131782 is in the same patent family as Japan 2004-146796.

This Information Disclosure Statement is being filed before the issuance of a first Office Action on the merits. Therefore, no fee under 37 C.F.R. § 1.97(c)(2) is believed due. Nevertheless, the Commissioner may charge Deposit Account No. 06-1205, should any fee be due for filing this paper.

Applicants request that the above information be considered by the Examiner and that a copy of the enclosed Form PTO-1449 be initialed and returned indicating that such information has been considered.

Applicants' undersigned attorney may be reached in our Costa Mesa, California office at (714) 540-8700. All correspondence should continue to be directed to our below-listed address.

Respectfully submitted,

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ORM PTO 1449 (modified)			03500.101486.	APPLICATION NO. 10/559,799			
	DEPARTMENT OF COMMERCE NT AND TRADEMARK OFFICE		APPLICANT TOMO	ONARI NAKAYA	WA, et al.		
LIST OF REFERENCES CITED BY APPLICANT(S) (Use several sheets if necessary) NOV 0 6 2006			INT'L FILING DATE:		GROUP		
	W. C.	Teneral	U.S. PATENT DOCUMENTS		T	FILING DATE	
EXAMINER INITIAL	DOCUMENT NUMBER	DATE	NAME	CLASS	SUBCLASS	IF APPROPRIATE	
	6,861,377	03/01/05	Hirai, et al.	438	781		
	6,107,117	08/22/00	Bao, et al.	438	99		
	2004/0131782	07/08/04	Hasei, et al.	427	337		
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		F	OREIGN PATENT DOCUMENTS			TRANSLATION	
	DOCUMENT NUMBER	DATE	COUNTRY	CLASS	SUBCLASS	YES/NO/ OR ABSTRACT	
	2004-146796	05/20/04	Japan			Abstract	
	2004-128469	04/22/04	Japan			Abstract	
	2004-63977	02/26/04	Japan			Abstract	
	2004-63975	02/26/04	Japan			Abstract	
	2004-6700	01/08/04	Japan			Abstract	
	10-190001	07/21/98	Japan			Abstract	
	10-190001	01723752				1	
	<u></u>	OTHER DOCUMEN	T(S) (Including Author, Title, Date, Pe	ertinent Pages, Etc.)			
	A Assadi et a	al "Field-effe	ect mobility of poly(3-h 8, pp. 195-197.	exylthiophene)' 	', Appl. Phys.	Lett., 	
	Zhenan Bao,	et al., "High-l Chem Mate	Performance Plastic Tra r., Vol. 9, No. 6, 1997, p				
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			k Insulators as the Cho unctional Materials, Vo	ice of Dielectric	cs in Organic	199-204.	
	1 1		DATE CONSIDERED				

*EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant. EXAMINER Sheet_1_ of __1_